

PHYS 425 - w5x3

Goal: Calculate heat capacity of a system of identical Fermions at low temp.

Low temp means $T \ll T_F = \frac{E_F}{k_B}$
↑
Fermi temp.

Beautiful calc that connect microscopic quantum theory to measurable macroscopic thermodynamic quantity.

Results apply to:

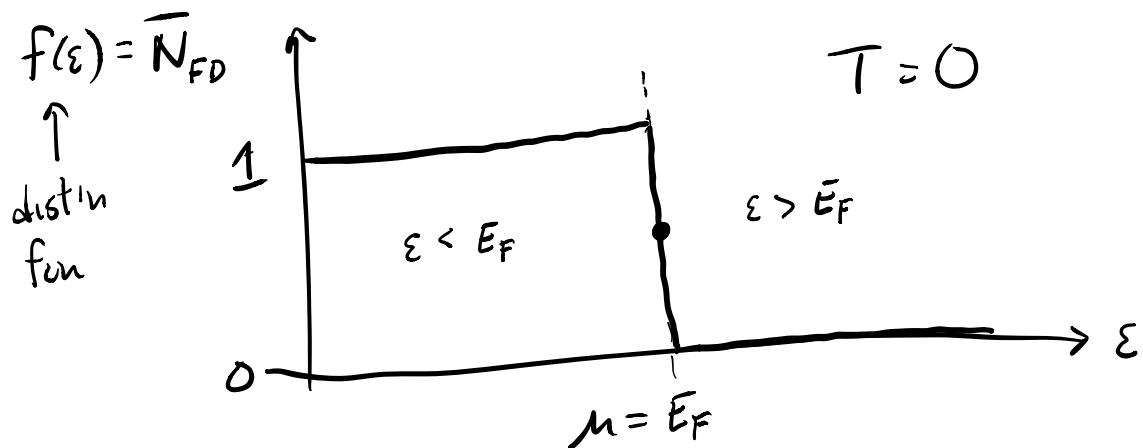
- conduction electrons in a metal. ($T_F \approx 10^4 - 10^5 \text{ K}$)
- neutrons in a neutron star
- ${}^3\text{He}$ atoms in ${}^4\text{He}$

Will show that $C_V \propto T$ when $T \ll T_F$

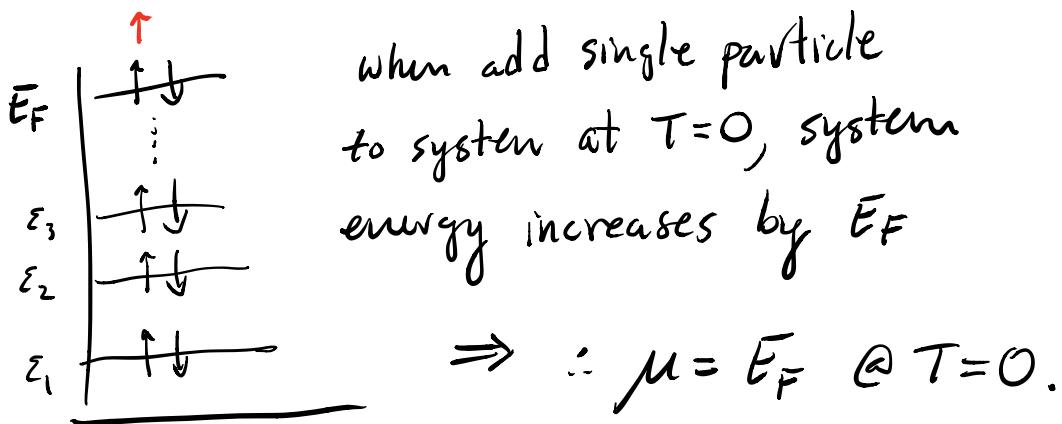
Density of States (DOS)

$D(\varepsilon) d\varepsilon$ tell us how many quantum states there are between energies of ε and $\varepsilon + d\varepsilon$

If we have a system of N Fermions at $T=0$, then all states below E_F are filled and all states above E_F empty.



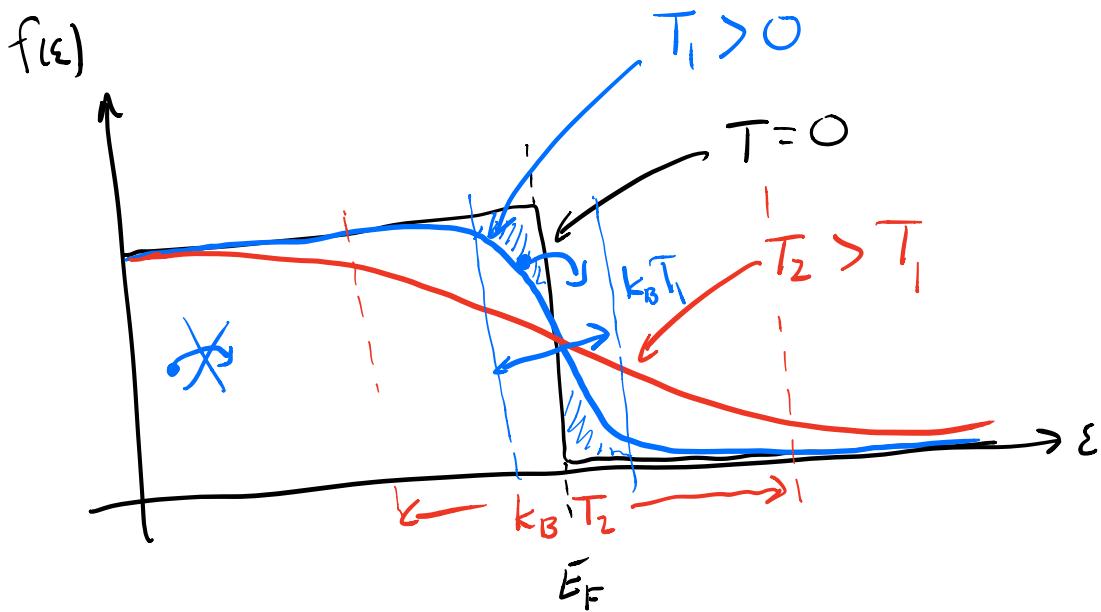
Recall chemical pot. μ tells us change in system energy when no. of particles is changed.



$$\therefore N = \underbrace{\int_0^{E_F} D(\epsilon) d\epsilon}_{\text{no. of states from } \epsilon=0 \text{ to } \epsilon=E_F} \quad \text{④}$$

The Fermi-Dirac dist'n fn $f(\epsilon)$ gives prob. that, at temp T , a state w/ energy ϵ is occupied.

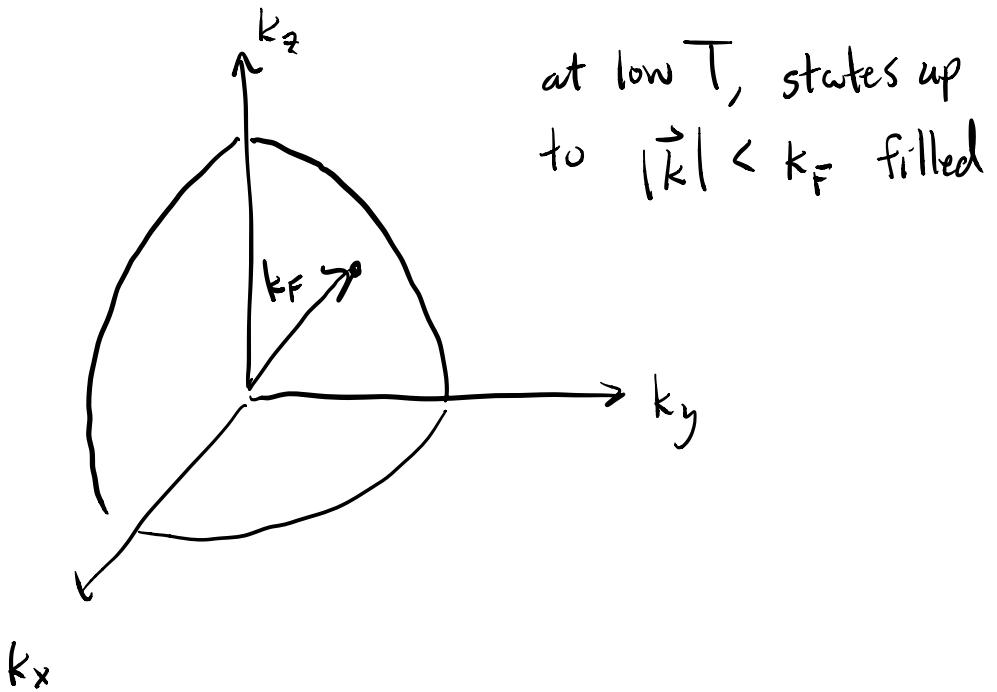
$$N = \int_0^{\infty} f(\epsilon) D(\epsilon) d\epsilon$$



For $0 < T \ll T_F$, only particles in states near E_F can be excited into higher energy states. Particles in low energy states don't have enough thermal energy ($k_B T$) to reach unoccupied states above E_F .

The functional form of $f(\epsilon)$ is

$$f(\epsilon) = \frac{1}{\exp\left(\frac{\epsilon - \mu}{k_B T}\right) + 1}$$



So another way to express N is

$$N = 2 \int \frac{d\vec{k}}{\left(\frac{\pi}{L}\right)^3} \quad \left(\frac{\pi}{L}\right)^3 = \frac{\pi^3}{V}$$

two particles per k -state. $|\vec{k}| \leq k_F$ $\left(\frac{\pi}{L}\right)^3 \leftarrow$ volume occupied per k -state

$$N = \frac{V}{\pi^3} \int_0^{k_F} \frac{1}{8} \sqrt{4\pi k^2} dk$$

↑ pos. oct.

$$= \frac{V}{\pi^2} \int_0^{k_F} k^2 dk \quad \leftarrow$$

$$\text{write } dk = \frac{d\epsilon}{\frac{dk}{d\epsilon}} d\epsilon \quad \frac{d\epsilon}{dk} = \frac{d}{dk} \left(\frac{\hbar^2 k^2}{2m} \right)$$

$$= \frac{\hbar^2 k}{m}$$

$$\therefore \frac{dk}{d\epsilon} = \frac{m}{\hbar^2 k}$$

$$\therefore N = \frac{V}{\pi^2} \int_0^{\epsilon_F} k^2 \frac{m}{\hbar^2 k} d\epsilon \quad \begin{aligned} \epsilon &= \frac{\hbar^2 k^2}{2m} \\ k &= \sqrt{\frac{2m\epsilon}{\hbar^2}} \end{aligned}$$

$$N = \frac{V}{\pi^2} \int_0^{\epsilon_F} \frac{\sqrt{2m\epsilon}}{\hbar^2} \frac{m}{\hbar^2} d\epsilon$$

$$= \int_0^{\epsilon_F} \frac{m\sqrt{\epsilon}}{\pi^2 \hbar^3} \sqrt{2m\epsilon} d\epsilon \left(\frac{2}{2} \right)$$

$$= \int_0^{\varepsilon_F} \boxed{\frac{V}{2\pi^2} \left(\frac{2m}{\hbar^2} \right)^{3/2} \sqrt{\varepsilon}} d\varepsilon$$

Compare to (8) $N = \int_0^{\varepsilon_F} \boxed{D(\varepsilon)} d\varepsilon$

\therefore DOS is

$$D(\varepsilon) = \frac{V}{2\pi^2} \left(\frac{2m}{\hbar^2} \right)^{3/2} \sqrt{\varepsilon}$$

Next goal is to use DOS to calc. heat capacity.

Internal Energy

$$U = \int_0^{\infty} \underbrace{\varepsilon f(\varepsilon)}_{\text{energy}} \underbrace{D(\varepsilon)}_{\substack{\text{prob. state is occupied} \\ \text{no. of states w/ energy } \varepsilon}} d\varepsilon$$

$$\rightarrow C_V = \left(\frac{\partial U}{\partial T} \right)_V = \int_0^\infty \varepsilon \frac{df(\varepsilon)}{dT} D(\varepsilon) d\varepsilon$$

First, note that

$$\begin{aligned} \rightarrow \int_0^\infty \frac{df(\varepsilon)}{dT} D(\varepsilon) d\varepsilon &= \underbrace{\frac{d}{dT} \int_0^\infty f(\varepsilon) D(\varepsilon) d\varepsilon}_N \\ &= \frac{dN}{dT} = O \left(\begin{matrix} \text{fixed} \\ \text{no. of particles} \end{matrix} \right) \end{aligned}$$

$$\begin{aligned} C_V &= \frac{\partial U}{\partial T} = \int_0^\infty \varepsilon \frac{df(\varepsilon)}{dT} D(\varepsilon) d\varepsilon - \mu \underbrace{\int_0^\infty \frac{df(\varepsilon)}{dT} D(\varepsilon) d\varepsilon}_O \\ &= \int_0^\infty (\varepsilon - \mu) \underbrace{\frac{df(\varepsilon)}{dT}}_{\text{replace}} D(\varepsilon) d\varepsilon \\ &\quad \# \end{aligned}$$

Evaluated $\frac{df}{dT}$

$$\frac{df(\epsilon)}{dT} = \frac{d}{dT} \frac{1}{\exp\left(\frac{\epsilon-\mu}{k_B T}\right) + 1} = \frac{+1}{\left(\exp\left(\frac{\epsilon-\mu}{k_B T}\right) + 1\right)^2}.$$

$$\left(\frac{+1}{k_B T^2} \exp\left(\frac{\epsilon-\mu}{k_B T}\right) \right)$$

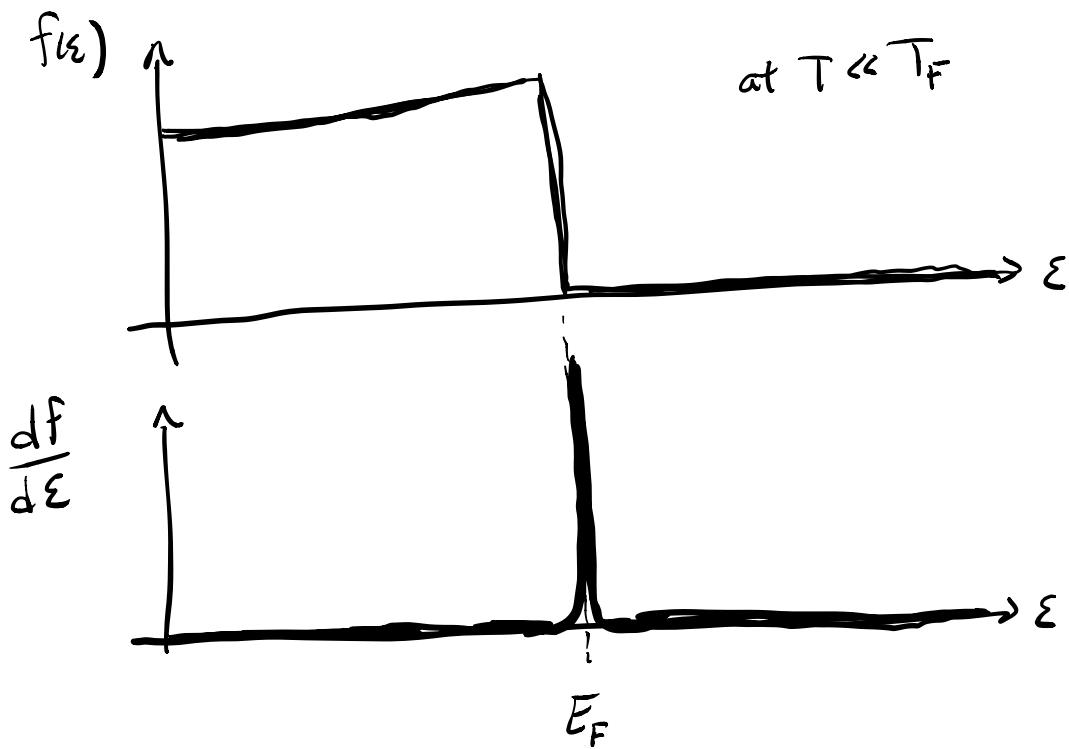
$$\frac{df(\epsilon)}{dT} = \frac{\frac{\epsilon-\mu}{k_B T^2} \exp\left(\frac{\epsilon-\mu}{k_B T}\right)}{\left(\exp\left(\frac{\epsilon-\mu}{k_B T}\right) + 1\right)^2}$$

$$\frac{df(\epsilon)}{d\epsilon} = \frac{d}{d\epsilon} \left(\frac{1}{\exp\left(\frac{\epsilon-\mu}{k_B T}\right) + 1} \right) = -\frac{1}{k_B T} \frac{\exp\left(\frac{\epsilon-\mu}{k_B T}\right)}{\left(\exp\left(\frac{\epsilon-\mu}{k_B T}\right) + 1\right)^2}$$

Notice that

$$\frac{df(\epsilon)}{dT} = -\left(\frac{\epsilon-\mu}{T}\right) \frac{df}{d\epsilon}$$
#

$$\therefore C_v = - \int_0^\infty \frac{(\varepsilon - \mu)^2}{T} \underbrace{\frac{df(\varepsilon)}{d\varepsilon}}_{\sim} D(\varepsilon) d\varepsilon$$



At low temps, $\frac{df(\varepsilon)}{d\varepsilon}$ is strongly peaked

at $\varepsilon = E_F$, \therefore in integral, can replace

$D(\varepsilon)$ w/ $D(E_F)$.

$$C_V \approx -D(E_F) \int_0^{\infty} \frac{(\varepsilon - \mu)^2}{T} \underbrace{\frac{df}{d\varepsilon}}_{df} d\varepsilon$$

Note that when $\varepsilon = \infty$, $f = 0$
 $\varepsilon = 0$, $f = 1$

$$C_V \approx -\frac{D(E_F)}{T} \int_1^0 (\varepsilon - \mu)^2 df$$

$$= \frac{D(E_F)}{T} \int_0^1 (\varepsilon - \mu)^2 df$$

If $f(\varepsilon) = \left[\exp\left(\frac{\varepsilon - \mu}{k_B T}\right) + 1 \right]^{-1}$

$$\frac{1}{f} - 1 = \exp\left(\frac{\varepsilon - \mu}{k_B T}\right)$$

or $k_B T \ln\left(\frac{1}{f} - 1\right) = \varepsilon - \mu$

$$\begin{aligned}
 C_V &= \frac{D(E_F)}{T} \int_0^1 (k_B T)^2 \left[\ln \left(\frac{1}{f} - 1 \right) \right]^2 df \\
 &= k_B^2 T D(E_F) \int_0^1 \left[\ln \left(\frac{1}{f} - 1 \right) \right]^2 df \\
 &\quad \underbrace{\qquad\qquad\qquad}_{\frac{\pi^2}{3} \text{ (exact sol'n)}}
 \end{aligned}$$

$$\text{Recall } D(E_F) = \frac{V}{2\pi^2} \left(\frac{2m}{\hbar^2} \right)^{3/2} \sqrt{E_F}$$

$$\text{also recall } E_F = \frac{\hbar^2}{2m} \left(\frac{3\pi^2 N}{V} \right)^{2/3}$$

$$\therefore E_F^{3/2} = \left(\frac{\hbar^2}{2m} \right)^{3/2} \frac{3\pi^2 N}{V}$$

$$C_V = k_B T \frac{N}{2\pi^2} \left(\frac{2m}{\hbar^2} \right)^{3/2} \frac{\pi^2}{3} \sqrt{E_F}$$

$$C_V = \frac{k_B T}{2} N \pi^2 \underbrace{\frac{V}{3\pi^2 N} \left(\frac{2m}{\hbar^2} \right)^{3/2}}_{\frac{1}{E_F^{3/2}}} \sqrt{E_F}$$

$$C_V = k_B T N \frac{\pi^2}{2} \frac{1}{E_F} = \frac{\pi^2}{2} k_B T N \frac{1}{E_F}$$

low-temp heat capacity of identical Fermions is:

$$C_V = \frac{\pi^2}{2} N k_B \frac{T}{T_F} \quad C_V \propto T$$